3.3 V / 5 V ECL Differential Receiver/Driver with Variable Output Swing and Internal Input Termination

Description

The MC100EP16VT is a differential receiver functionally equivalent to the 100EP16 with input pins controlling the amplitude of the outputs (pin 1) and providing an internal termination network (pin 4).

The V_{CTRL} input pin controls the output amplitude of the EP16VT and is referenced to V_{CC} . (See Figure 4.) The operational range of the V_{CTRL} input is from $\leq V_{BB}$ (a supply at V_{CC} –1.42 V, maximum output amplitude) to V_{CC} (minimum output amplitude). V_{BB} is an externally supplied voltage equal to V_{CC} –1.42 V (See Figures 2 and Figure 3). A variable resistor between V_{CC} and V_{BB} , with the wiper driving V_{CTRL} , can control the output amplitude. Typical application circuits and a V_{CTRL} Voltage vs. Output Amplitude graph are described in this data sheet. When left open, the V_{CTRL} pin will be internally pulled down to V_{EE} and operate as a standard EP16, with 100% output amplitude.

The V_{TT} input pin offers an internal termination network for a 50 Ω line impedance environment, shown in Figure 1. For further reference, see Application Note <u>AND8020</u>, Termination of ECL Logic Devices. Input considerations are required for D and \overline{D} under no signal conditions to prevent instability.

Special considerations are required for differential inputs under No Signal conditions to prevent instability.

Features

- 220 ps Propagation Delay
- Maximum Frequency > 4 GHz Typical (See Graph)
- The 100 Series Contains Temperature Compensation
- PECL Mode Operating Range:
 - $V_{CC} = 3.0 \text{ V}$ to 5.5 V with $V_{EE} = 0 \text{ V}$
- NECL Mode Operating Range:
 - $V_{CC} = 0 \text{ V}$ with $V_{EE} = -3.0 \text{ V}$ to -5.5 V
- Open Input Default State
- 50 Ω Internal Termination Resistor
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

1



ON Semiconductor®

www.onsemi.com



SOIC-8 NB D SUFFIX CASE 751-07



TSSOP-8 DT SUFFIX CASE 948R-02



DFN-8 MN SUFFIX CASE 506AA

MARKING DIAGRAMS*







A = Assembly Location

= Wafer Lot

′ = Year

W = Work Week

M = Date Code

■ = Pb-Free Package

(Note: Microdot may be in either location)

*For additional marking information, refer to Application Note <u>AND8002/D</u>.

ORDERING INFORMATION

Device	Package	Shipping [†]
MC100EP16VTDG	SOIC-8 NB (Pb-Free)	98 Units/Tube
MC100EP16VTDR2G	SOIC-8 NB (Pb-Free)	2500/Tape & Reel
MC100EP16VTDTG	TSSOP-8 (Pb-Free)	100 Units/Tube
MC100EP16VTDTR2G	TSSOP-8 (Pb-Free)	2500/Tape & Reel
MC100EP16VTMNR4G	DFN-8 (Pb-Free)	1000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

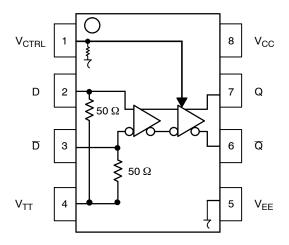


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram

Table 1. PIN DESCRIPTION

PIN	FUNCTION
D, \overline{D}	ECL Data Inputs
Q, Q	ECL Data Outputs
V _{CTRL} *	Output Swing Control
V _{TT}	Termination Supply
V _{CC}	Positive Supply
V _{EE}	Negative Supply
EP	(DFN-8 only) Thermal exposed pad must be connected to a sufficient thermal conduit. Electrically connect to the most negative supply (GND) or leave unconnected, floating open.

^{*} Pin will default LOW when left open.

Table 2. ATTRIBUTES

Characteristics	Value	Value			
Internal Input Pulldown Resistor	75	kΩ			
Internal Input Pullup Resistor	N,	'A			
ESD Protection Human Body Model Machine Model Charged Device Model	> 4 kV > 200 V > 2 kV				
Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1)	Pb-Free Pkg				
SOIC-8 NB TSSOP-8 DFN-8	Lev Lev Lev	el 3			
Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0	@ 0.125 in			
Transistor Count	140 D	evices			
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test					

^{1.} For additional information, see Application Note AND8003/D.

Table 3. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		6	V
V _{EE}	NECL Mode Power Supply	V _{CC} = 0 V		-6	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	$ V_I \leq V_{CC} \\ V_I \geq V_{EE} $	6 -6	V
l _{out}	Output Current	Continuous Surge		50 100	mA
T _A	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
$\theta_{\sf JA}$	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	SOIC-8 NB	190 130	°C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction-to-Case)	Standard Board	SOIC-8 NB	41 to 44	°C/W
$\theta_{\sf JA}$	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	TSSOP-8	185 140	°C/W
θ _{JC}	Thermal Resistance (Junction-to-Case)	Standard Board	TSSOP-8	41 to 44 ± 5%	°C/W
$\theta_{\sf JA}$	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	DFN-8	129 84	°C/W
T _{sol}	Wave Solder (Pb-Free)	<2 to 3 sec @ 260°C		265	°C
$\theta_{\sf JC}$	Thermal Resistance (Junction-to-Case)	(Note 1)	DFN-8	35 to 40	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 4. DC CHARACTERISTICS, PECL (V_{CC} = 3.3 V, V_{EE} = 0 V (Note 1))

		-40°C		25°C							
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	30	36	42	31	38	44	32	40	48	mA
V _{OH}	Output HIGH Voltage (Max Swing) (Note 2) V _{CC} ≥ V _{CTRL} ≥ V _{EE}	2155		2405	2155		2405	2155		2405	mV
V _{OL}	Output LOW Voltage (Max Swing) (Note 2) $V_{CTRL} \le V_{BB}$	1355	1490	1605	1355	1520	1605	1355	1520	1605	mV
	V _{CC} ≥ V _{CTRL} > V _{BB}		See Fig.2			See Fig.2			See Fig.2		
	V _{CTRL} = V _{CC} (Min Swing)	2105	2230	2355	2095	2220	2345	2065	2190	2315	
V _{IH}	D, D Input HIGH Voltage (Single-Ended)	2075		2420	2075		2420	2075		2420	mV
V _{IL}	D, D Input LOW Voltage (Single-Ended)	1355		1675	1355		1675	1355		1675	mV
V _{CTRL}	Input Voltage (V _{CTRL})	V _{EE}		V_{CC}	V _{EE}		V_{CC}	V _{EE}		V_{CC}	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3)	2.0		2.9	2.0		2.9	2.0		2.9	٧
I _{IH}	Input HIGH Current (V _{TT} Open)			150			150			150	μА
I _{IL}	Input LOW Current (V _{TT} Open)	-150			-150			-150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

^{1.} JEDEC standard multilayer board - 2S2P (2 signal, 2 power)

Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.3 V to -2.2 V.
 All loading with 50 Ω to V_{CC} - 2.0 V. V_{OH} does not change with V_{CTRL}. V_{OL} changes with V_{CTRL}. V_{CTRL} is referenced to V_{CC}.
 V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential

Table 5. DC CHARACTERISTICS, PECL ($V_{CC} = 5.0 \text{ V}$, $V_{EE} = 0 \text{ V}$ (Note 1))

		-40°C		25°C							
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	30	36	42	31	38	44	32	40	48	mA
V _{OH}	Output HIGH Voltage (Note 2) VCC > VCTRL > VEE	3855	3980	4105	3855	3980	4105	3855	3980	4105	mV
V _{OL}	Output LOW Voltage (Max Swing) (Note 2) V _{CTRL} ≤ V _{BB}	3055	3190	3305	3055	3220	3305	3055	3220	3305	mV
	VCC ≥ V _{CTRL} > V _{BB}		See Fig.2			See Fig.2			See Fig.2		
	V _{CTRL} = V _{CC} (Min Swing)	3805	3930	4055	3795	3920	4045	3765	3890	4015	
V _{IH}	D, D Input HIGH Voltage (Single-Ended)	3775		4120	3775		4120	3775		4120	mV
V _{IL}	D, D Input LOW Voltage (Single-Ended)	3055		3375	3055		3375	3055		3375	mV
V _{CTRL}	Input Voltage (V _{CTRL})	V _{EE}		V_{CC}	V_{EE}		V_{CC}	V _{EE}		V_{CC}	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3)	2.0		4.6	2.0		4.6	2.0		4.6	V
I _{IH}	Input HIGH Current (V _{TT} Open)			150			150			150	μΑ
I _{IL}	Input LOW Current (V _{TT} Open)	-150			-150			-150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +2.0 V to -0.5 V.
 All loading with 50 Ω to V_{CC} 2.0 V. V_{OH} does not change with V_{CTRL}. V_{OL} changes with V_{CTRL}. V_{CTRL} is referenced to V_{CC}.
 V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

Table 6. DC CHARACTERISTICS, NECL (V_{CC} = 0 V; V_{EE} = -5.5 V to -3.0 V (Note 1))

		-40°C			25°C						
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	30	36	42	31	38	44	32	40	48	mA
V _{OH}	Output HIGH Voltage (Note 2) VCC > VCTRL > VEE	-1145	-1020	-895	-1145	-1020	-895	-1145	-1020	-895	mV
V _{OL}	Output LOW Voltage (Max Swing) (Note 2) V _{CTRL} ≤ V _{BB}	-1945	-1810	-1695	-1945	-1780	-1695	-1945	-1780	-1695	mV
	VCC ≥ V _{CTRL} > V _{BB}		See Fig.2			See Fig.2			See Fig.2		
	V _{CTRL} = V _{CC} (Min Swing)	-1195	-1070	-945	-1205	-1080	-955	-1235	-1110	-985	
V _{IH}	D, D Input HIGH Voltage (Single-Ended)	-1225		-880	-1225		-880	-1225		-880	mV
V _{IL}	D, D Input LOW Voltage (Single-Ended)	-1945		-1625	-1945		-1625	-1945		-1625	mV
V _{CTRL}	Input Voltage (V _{CTRL})	V_{EE}		V_{CC}	V_{EE}		V_{CC}	V_{EE}		V_{CC}	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3)	V _{EE}	+2.0	-0.4	V _{EE}	+2.0	-0.4	V _{EE}	+2.0	-0.4	V
I _{IH}	Input HIGH Current (V _{TT} Open)			150			150			150	μΑ
I _{IL}	Input LOW Current (V _{TT} Open)	-150			-150			-150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- Input and output parameters vary 1:1 with V_{CC}.
 All loading with 50 Ω to V_{CC} 2.0 V. V_{OH} does not change with V_{CTRL}. V_{OL} changes with V_{CTRL}. V_{CTRL} is referenced to V_{CC}.
 V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential

Table 7. AC CHARACTERISTICS ($V_{CC} = 0 \text{ V}$; $V_{EE} = -3.0 \text{ V}$ to -5.5 V or $V_{CC} = 3.0 \text{ V}$ to 5.5 V; $V_{EE} = 0 \text{ V}$ (Note 1))

		-40°C			25°C						
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{max}	Maximum Toggle Frequency (See Figure 8. F _{max} /JITTER)		> 4			> 4			> 4		GHz
t _{PLH} , t _{PHL}	Propagation Delay to Output Differential Max Swing Min Swing	250 200	300 250	350 300	250 200	300 250	350 300	250 200	300 250	350 300	ps
tskew	Duty Cycle Skew (Note 2)		5.0	20		5.0	20		5.0	20	ps
t _{JITTER}	Cycle-to-Cycle Jitter (See Figure 8. F _{max} /JITTER)		0.2	< 1		0.2	< 1		0.2	< 1	ps
V _{PP}	Input Voltage Swing (Differential Configuration) (Note 3)	150	800	1200	150	800	1200	150	800	1200	mV
t _r , t _f	Output Rise/Fall Times Max Swing Q (20% – 80%) Min Swing	70 30	120 80	170 130	80 20	130 70	180 120	100 20	150 70	200 120	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 1. Measured using a 750 mV source, 50% duty cycle clock source. All loading with 50 Ω to V_{CC} 2.0 V.
- 2. Skew is measured between outputs under identical transitions. Duty cycle skew is defined only for differential operation when the delays are measured from the cross point of the inputs to the cross point of the outputs.
- 3. VPP(min) is minimum input swing for which AC parameters are guaranteed.

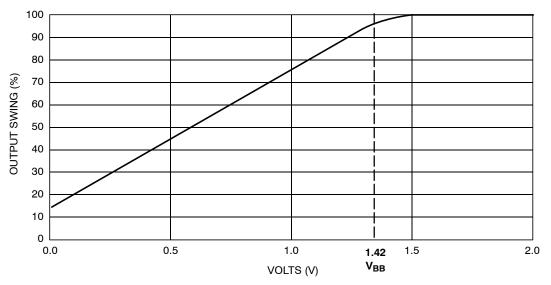


Figure 2. V_{CC} – V_{CTRL} (pin #1)

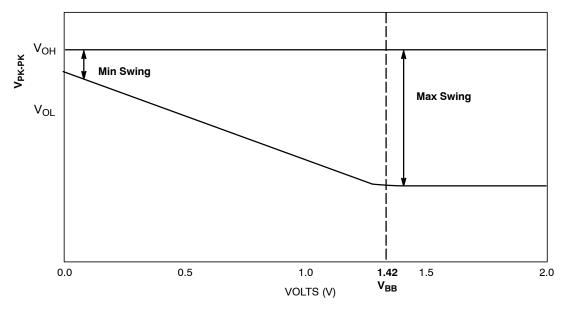


Figure 3. V_{CC} - V_{CTRL}

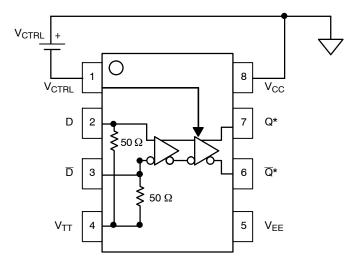


Figure 4. Voltage Source Implementation, V_{CTRL} Pin 1

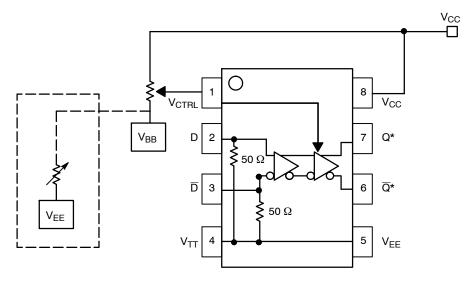


Figure 5. Alternative Implementations, V_{CTRL} Pin 1

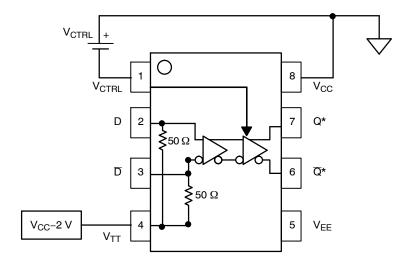


Figure 6. Standard Termination Method, V_{TT} Pin 4

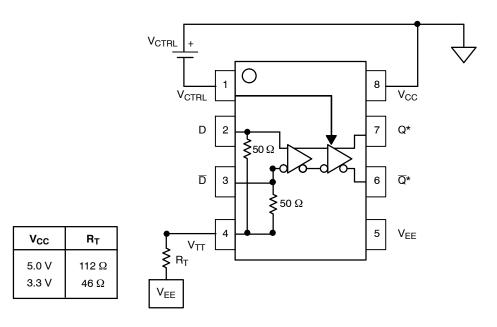


Figure 7. Alternate "Y" Termination Method, V_{TT} Pin 4

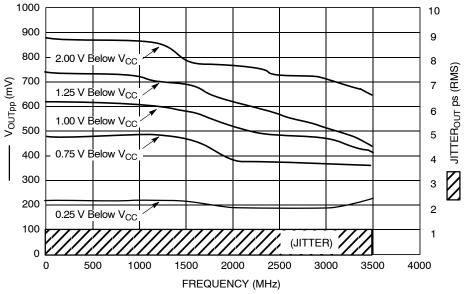


Figure 8. F_{max}/Jitter

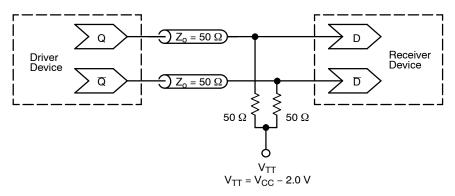


Figure 9. Typical Termination for Output Driver and Device Evaluation (See Application Note <u>AND8020/D</u> – Termination of ECL Logic Devices.)

Resource Reference of Application Notes

AN1405/D - ECL Clock Distribution Techniques

AN1406/D - Designing with PECL (ECL at +5.0 V)

AN1503/D - ECLinPS™ I/O SPiCE Modeling Kit

AN1504/D - Metastability and the ECLinPS Family

AN1568/D - Interfacing Between LVDS and ECL

AN1672/D - The ECL Translator Guide

AND8001/D - Odd Number Counters Design

AND8002/D - Marking and Date Codes

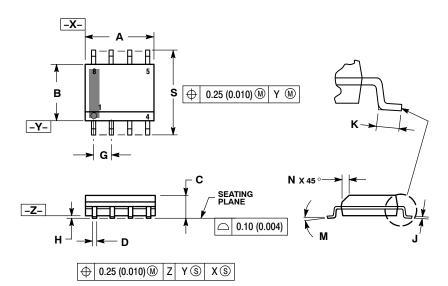
AND8020/D - Termination of ECL Logic Devices

AND8066/D - Interfacing with ECLinPS

AND8090/D - AC Characteristics of ECL Devices

PACKAGE DIMENSIONS

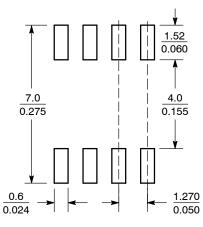
SOIC-8 NB CASE 751-07 **ISSUE AK**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
 6. 751–01 THRU 751–06 ARE OBSOLETE. NEW
- 751–01 THRU 751–06 ARE OBSOLETE. NEW STANDARD IS 751–07.

	MILLIN	IETERS	INC	HES			
DIM	MIN	MAX	MIN	MAX			
Α	4.80	5.00	0.189	0.197			
В	3.80	4.00	0.150	0.157			
С	1.35	1.75	0.053	0.069			
D	0.33	0.51	0.013	0.020			
G	1.27	7 BSC	0.050 BSC				
Н	0.10	0.25	0.004	0.010			
J	0.19 0.2		0.007	0.010			
K	0.40 1.27		0.016	0.050			
M	0 °	8 °	0 °	8 °			
N	0.25	0.50	0.010	0.020			
S	5.80	6.20	0.228	0.244			

SOLDERING FOOTPRINT*

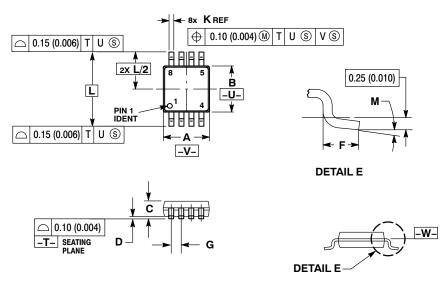


(mm inches) SCALE 6:1

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TSSOP-8 CASE 948R-02 **ISSUE A**



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSION A DOES NOT INCLLIDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

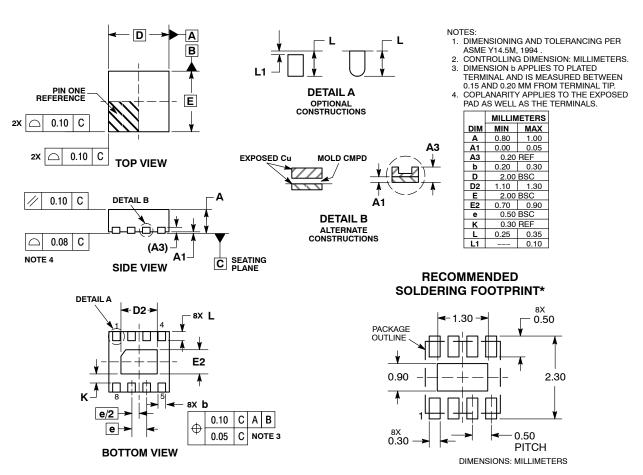
 6. DIMENSION A AND B ARE TO BE

 - DIMENSION A AND B ARE TO BE
 DETERMINED AT DATUM PLANE -W-.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.114	0.122
В	2.90	3.10	0.114	0.122
С	0.80	1.10	0.031	0.043
D	0.05	0.15	0.002	0.006
F	0.40	0.70	0.016	0.028
G	0.65	BSC	0.026	BSC
K	0.25	0.40	0.010	0.016
L	4.90	BSC	0.193	BSC
M	0°	6 °	0°	6°

PACKAGE DIMENSIONS

DFN-8 2x2, 0.5P CASE 506AA ISSUE F



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, <u>SOLDERRM/D</u>.

ECLinPS is a registered trademark of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor datas sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify a

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center

Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor:

MC100EP16VTDG MC100EP16VTDR2G MC100EP16VTDTG MC100EP16VTDTR2G